$^{10}$ J. Krieger and M. Nightingale, Phys. Rev. B <u>4</u>, 1266 (1971).

<sup>11</sup>S. Von Molnar and M. Shafer, J. Appl. Phys. <u>41</u>, 1093 (1970).

<sup>12</sup>J. Axe, J. Phys. Chem. Solids 30, 1403 (1969).

<sup>13</sup>M. Freiser, F. Holtzberg, S. Methfessel, G. Pettit,

M. Shafer, and J. Suits, Helv. Phys. Acta <u>41</u>, 832 (1968). The use of optical data to estimate  $E_i$  may be somewhat questionable if the final state of the optical transition differs from the conduction band state. However, this value of  $E_i$  is consistent with an analysis of the data given in Refs. 2, 4b, 8, and 11.

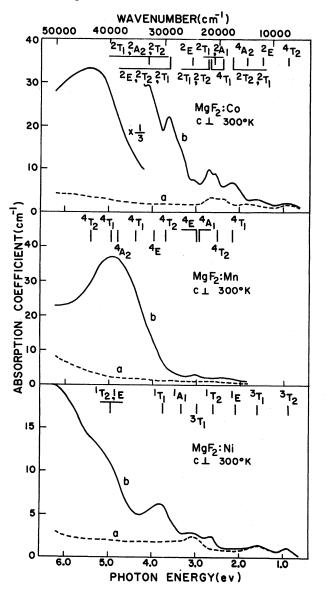
## Enhancement of 3d Impurity-Ion Spin-Forbidden Absorption by Color Centers in MgF<sub>2</sub><sup>+</sup>

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The spin-forbidden optical transitions of  $\text{Co}^{2+}$ ,  $\text{Ni}^{2+}$ , and  $\text{Mn}^{2+}$  have been observed in doped crystals of MgF<sub>2</sub> following both  $\gamma$  and electron irradiation. Radiation-induced F centers trapped at impurity sites appear to reduce the forbiddenness significantly for many of the transitions. Oscillator strength increases of up to  $10^3$  have been recorded.

Over the past decade or so the excellent research of McClure, Ferguson, and their co-workers and others<sup>1-4</sup> has considerably extended our knowledge of the 3d impurity-ion transitions in various crystal fields. Unfortunately, these transitions are strongly forbidden and difficult to observe experimentally. In cases of  $O_h$  crystal field symmetry many of these transitions are spin and parity forbidden having extremely small oscillator strengths in the range of  $10^{-7}$ . This is a severe limitation since only a few absorption bands can be studied even in relatively thick crystals. High-resolution optical data for more of these transitions would greatly improve our understanding of the spin-orbit coupling, exchange effects, and the interaction of the 3d ions with lattice phonons. Therefore, it would be highly desirable to be able to increase the intensity of these strongly forbidden transitions. Recently Sell and Stokowski<sup>5</sup> have hinted at this possibility. They observed in MnF<sub>2</sub> a small increase in the  $Mn^{2+}$  absorption induced by the presence of Ca impurities. In this Letter we report that oscillator strengths for Co<sup>2+</sup>, Ni<sup>2+</sup>, and Mn<sup>2+</sup> transitions in MgF<sub>2</sub> can be increased up to 3 orders of magnitude with the aid of radiation-induced color centers. Such large changes also imply that these defect-perturbed transitions might be useful for photochromic devices.<sup>6</sup>

FIG. 1. Room-temperature absorption spectra illustrating the enhancement of the spin-forbidden transitions for  $\operatorname{Co}^{2^+}$ ,  $\operatorname{Ni}^{2^+}$ , and  $\operatorname{Mn}^{2^+}$  impurity ions in MgF<sub>2</sub>. Spectra labeled *a* represent the absorption in unirradiated crystals while the curves labeled *b* show the absorption following  $\gamma$  irradiation.



Ме	3F2:Mn		MgF <sub>2</sub> :N1			
Assignment Peak $(0_h)$ Position $(0_h) \to (cm^{-1})$	<u>Oscillator</u> Before Irradiation	<u>Strength</u> After Irradiation	'n	<u>Oscillato</u> Before Irradiation	<u>r Strength</u> After Irradiation	
	$\left\{\begin{array}{c} 2.7 \times 10^{-7} \\ 1.9 \times 10^{-7} \\ 1.1 \times 10^{-7} \end{array}\right\}$	$2.9 \times 10^{-5}$ 1.0 x 10 <sup>-4</sup>	${}^{3}A_{2g}({}^{3}F) \rightarrow (cm^{-1})$ ${}^{3}T_{2g}({}^{3}F) \rightarrow 7407$ ${}^{3}T_{1g}({}^{3}F)  13  158$ ${}^{1}E_{g}({}^{1}D)  16  949$ ${}^{1}T_{2g}({}^{1}D)  21  277$	$8.6 \times 10^{-6}$  1.8 x 10 <sup>-7</sup>	$9.4 \times 10^{-6}$  8.8 x 10 <sup>-6</sup>	
${}^{4}T_{2g}({}^{4}D)$ 29 851 ${}^{4}E_{g}({}^{4}D)$ 31 847	$2.0 \times 10^{-7}$ 2.9 x 10 <sup>-7</sup>		${}^{3}\mathrm{T}_{1g}({}^{3}\mathrm{P})$ 24 390 ${}^{1}\mathrm{A}_{1g}({}^{1}\mathrm{G})$ 27 027	1.9 x 10 <sup>-5</sup>	1.7 x 10 <sup>-5</sup>	
${}^{4}T_{1g}({}^{4}P)$ 35 088 ${}^{4}A_{2g}({}^{4}F)$ 38 022	$3.3 \times 10^{-7}$		$ \left. \begin{array}{c} {}^{1}\mathrm{T}_{1g}({}^{1}\mathrm{G}) & 30 \ 120 \\ \\ {}^{1}\mathrm{T}_{2g}({}^{1}\mathrm{G}) \\ \\ {}^{1}\mathrm{E}_{g}({}^{1}\mathrm{G}) \end{array} \right\} 40 \ 000 $	<4.1 x 10 <sup>-8</sup>	$3.5 \times 10^{-5}$	
${}^{4}T_{1g}({}^{4}F)$ 40 000 ${}^{4}T_{2g}({}^{4}F)$ 43 554			1 <sub>E</sub> ( <sup>1</sup> G) 40 000	<3.4 x 10 <sup>-7</sup>	1.5 x 10 <sup>-5</sup>	
-2g + 3 554						

TABLE I.  $Mn^{2+}$  and  $Ni^{2+}$  transitions in MgF<sub>2</sub> crystals.

The 3d transition ions have been studied in detail in many different lattices and assignments for the various observed absorption bands have been made. In particular, the observed transitions for  $Mn^{2+}$  and  $Co^{2+}$  have been assigned in  $MnF_{2}$ ,<sup>4,7,8</sup> and those for  $Ni^{2+}$  in  $MgF_{2}$ .<sup>3</sup> Since MnF<sub>2</sub> and MgF<sub>2</sub> have the same rutile structure, it is expected that the transitions of the 3d impurity ions will be very similar in both hosts. Most investigators have made the approximation that the positive ion site has  $O_h$  symmetry in this lattice, although this is not quite the case. The curves labeled a in Fig. 1 illustrate the roomtemperature absorption for as-grown crystals of MgF<sub>2</sub>:Co, MgF<sub>2</sub>:Ni, and MgF<sub>2</sub>:Mn in the 200- to 2000-nm spectral range. The crystals studied were obtained from Optovac and contain about 2.0 at.% Co, 0.75 at.% Ni, and 0.05 at.% Mn, respectively. These impurity concentrations were used to calculate the oscillator strengths for the observed transitions in curves a of Fig. 1. The values are listed in Tables I and II and are very close to those reported previously.<sup>3,7-9</sup>

When MgF<sub>2</sub> crystals are irradiated with elec-

trons or  $\gamma$  rays at room temperature, F centers, negative-ion vacancies each having a trapped electron, are formed. At room temperature these defects are mobile under irradiation and can move through the crystal to form F-aggregate centers or to be trapped adjacent to impurity sites. In the latter case if the impurities are 3d transition ions, the optical transitions of these ions can be affected by changes in site symmetry from approximately  $O_h$  to  $C_{4v}$  and also by exchange between the paramagnetic F-center electron and the 3d electrons. It is expected that such interactions would markedly increase the oscillator strengths for these transitions. The curves labeled b in Fig. 1 illustrate the optical absorption observed for the doped MgF<sub>2</sub> samples after a (10<sup>7</sup>-R)  $\gamma$  irradiation. A dramatic increase of several orders of magnitude in intensity is observed for the previously spin-forbidden transitions as shown by Table I and Table II. However, the spin-allowed transitions, which are observable in the unirradiated crystals, do not increase significantly. This suggests that the dominant effect is due to exchange and that changes in site symmetry do not

MgF2:Co									
Assignment (0 <sub>h</sub> ) <sup>4</sup> T <sub>1g</sub> ( <sup>4</sup> F)→	Peak Position (cm <sup>-1</sup> )	Oscillator Strength Before After Irradiation Irradiatio							
<sup>4</sup> T <sub>2g</sub> ( <sup>4</sup> F)	7 353	$3.0 \times 10^{-6}$	$3.4 \times 10^{-6}$						
<sup>2</sup> Eg( <sup>2</sup> G)	11 765	$2.5 \times 10^{-8}$	$1.5 \times 10^{-6}$						
<sup>4</sup> A <sub>2g</sub> ( <sup>4</sup> F)	14 706	$1.6 \times 10^{-6}$	$1.5 \times 10^{-6}$						
$2^{7}$	17 331	$8.4 \times 10^{-8}$	$1.0 \times 10^{-5}$						
<sup>4</sup> T <sub>1g</sub> ( <sup>4</sup> P) {	19 231 21 645 <b>}</b>	$2.1 \times 10^{-5}$	$2.1 \times 10^{-5}$						
$\left. \left. \begin{array}{c} {}^{2}\mathbf{T}_{1g}({}^{2}\mathbf{H}) \\ {}^{2}\mathbf{A}_{1g}({}^{2}\mathbf{G}) \end{array} \right\}$	20 534		3.6 x 10 <sup>-6</sup>						
$2_{T_{1g}} + 2_{2g} + 2_{2g} + 2_{H}$	21 739		4.8 x 10 <sup>-6</sup>						
<sup>2</sup> E <sub>g</sub> ( <sup>2</sup> H)	24 938	$2.9 \times 10^{-8}$	$1.5 \times 10^{-6}$						
$\left. \left. \left. \begin{array}{c} {}^{2_{\mathrm{T}}}{}_{\mathrm{1g}} \left( {}^{2_{\mathrm{P}}} \right) \\ {}^{2_{\mathrm{E}_{\mathrm{g}}}}{}_{,}{}^{2_{\mathrm{T}}}{}_{\mathrm{2g}} \left( {}^{2_{\mathrm{D}}} \right) \end{array} \right\} \right.$	29 240	<6.4 x 10 <sup>-8</sup>	3.2 x 10 <sup>-5</sup>						
$\left\{ \frac{2^{T_{1g}}^{2} + A_{2g}^{2}(2^{F})}{2^{T_{2g}^{2}}(2^{F})} \right\}$	32 787	<6.5 x 10 <sup>-8</sup>	6.1 x 10 <sup>-5</sup>						

TABLE II.  $Co^{2^+}$  transitions in MgF<sub>2</sub> crystals.

have an appreciable effect on the transitions. Possible assignments for each of the absorption bands are shown in Fig. 1. These tentative assignments were made using the results of previous investigators<sup>3, 4, 7, 10</sup> and the calculations of Liehr.<sup>11</sup>

It is difficult to introduce appreciable amounts of  $Mn^{2+}$  into  $MgF_2$ . Therefore, since the  $Mn^{2+}$ transitions are very weak, it is enlightening to study the excitation spectrum by monitoring the emission from this impurity. Such a spectrum is shown in Fig. 2 and brings out much more detail than the absorption spectrum illustrated in Fig. 1. In fact, the assignments shown on Fig. 1 and in Table I were made from these data. It is interesting to note that the excitation spectrum is almost identical to that<sup>12, 13</sup> for  $Mn^{2+}$  in KMgF<sub>3</sub>; however, the luminescence band occurs at a slightly lower energy. The emisstion spectra from MgF<sub>2</sub>:Mn are portrayed in the inset of Fig. 2.

In summary, it appears that it is possible with low doses of  $\gamma$  rays or electrons to increase the magnitude of the absorption bands for the 3*d* tran-

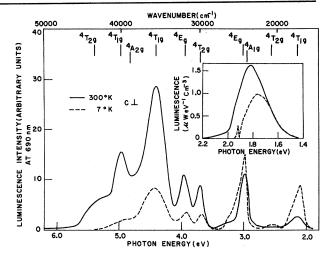


FIG. 2. Excitation spectra of an electron-irradiated  $MgF_2$ :Mn crystal at 300 and 7°K. The inset illustrates the emission spectra for  $Mn^{2+}$  in the irradiated crystal.

sition metal ions sufficiently that they can be studied in detail. We realize that the presence of a defect as a nearest neighbor will cause perturbations, but the gain in intensity far outweighs this disadvantage. Another difficulty is the Fband absorption which occurs at 260 nm in pure MgF<sub>2</sub> crystals.<sup>14</sup> For these low radiation doses only a small F band should be formed, but the possibility of its presence precludes assignments in the uv region. It should be stated that the enhancement of divalent 3d impurity ions may be limited to materials such as MgF, and KMgF<sub>3</sub>. Ikeya<sup>15, 16</sup> has irradiated NaCl:Mn and found that the radiation changes the valence state of Mn<sup>2+</sup> to Mn<sup>1+</sup> and Mn<sup>0</sup>. Jain and Lal<sup>17</sup> find similar effects for NaCl:Co. This, of course, would reduce the possibility for this type of investigation in NaCl.

<sup>4</sup>J. Ferguson, D. L. Wood, and K. Knox, J. Chem. Phys. <u>39</u>, 881 (1963).

<sup>5</sup>D. D. Sell and S. E. Stokowski, Phys. Rev. B <u>3</u>, 2844 (1971).

<sup>6</sup>B. W. Faughnan, D. L. Staebler, and Z. J. Kiss, Appl. Solid State Sci. <u>2</u>, 107 (1971).

<sup>7</sup>J. W. Stout, J. Chem. Phys. <u>31</u>, 709 (1959).

<sup>†</sup>Work supported by the National Science Foundation Grant No. GP-29545.

<sup>&</sup>lt;sup>1</sup>D. S. McClure, in *Solid State Physics*, edited by H. Ehrenreich, F. Seitz, and D. Turnbull (Academic Press, New York, 1959), Vol. 9, p. 399.

<sup>&</sup>lt;sup>2</sup>N. S. Hush and R. J. M. Hobbs, in *Progress in In*organic Chemistry, edited by F. A. Cotton (Interscience, New York, 1968), Vol. 10, p. 259.

<sup>&</sup>lt;sup>3</sup>J. Ferguson, H. J. Guggenheim, H. Kamimura, and Y. Tanabe, J. Chem. Phys. <u>42</u>, 775 (1965).

<sup>8</sup> R. F. Blunt,	J.	Chem.	Phys.	44,	2317	(1966).	
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<sup>9</sup>J. Ferguson, H. J. Guggenheim, and D. L. Wood, J. Chem. Phys. 40, 822 (1964).

<sup>10</sup>Y. Tanabe and S. Sugano, J. Phys. Soc. Jap. <u>9</u>, 753 (1954).

<sup>11</sup>A. D. Liehr, J. Phys. Chem. 67, 1314 (1963).

 $^{12}$ W. E. Vehse and W. A. Sibley, Phys. Rev. B (to be published).

<sup>13</sup>W. A. Sibley, S. I. Yun, and W. E. Vehse, to be pub-

lished.

<sup>14</sup>W. A. Sibley and O. E. Facey, Phys. Rev. <u>174</u>, 1076 (1968).

<sup>15</sup>M. Ikeya and N. Itoh, J. Phys. Soc. Jap. <u>29</u>, 1295 (1970).

<sup>16</sup>M. Ikeya, Phys. Status Solidi (b) <u>51</u>, 407 (1972). <sup>17</sup>S. C. Jain and K. Lal, in *Non-Metallic Crystals*, edited by S. C. Jain and L. T. Chadderton (Gordon and

Breach, New York, 1969), p. 219.

## New Domain-Wall Configuration for Magnetic Bubbles

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A theory based on the hypothesis that the perimeter wall of a magnetic bubble may be composed of alternate Bloch and Néel segments is shown to account quantitatively for the anomalous dependence of diameter on bias field of the recently observed "hard" bubbles in garnet films.

Recently a new class of cylindrical magnetic domains or bubbles has been observed.<sup>1</sup> These new bubbles, designated as hard bubbles, have static and dynamic properties substantially different from those of normal bubbles. Their most anomalous static property is their much larger range of stability in both applied-field and diameter variations. Furthermore any material that allows these hard bubbles also exhibits a range of intermediate bubbles that collapse at fields and diameters intermediate between those of the hard and normal bubbles.

In this Letter we wish to show how the static properties of these hard and intermediate bubbles can be quantitatively explained by assuming the presence of Néel segments in the Bloch wall that forms the perimeter of the bubbles.<sup>2,3</sup>

We therefore consider a hard bubble as having a wall as shown in Fig. 1(a). Here the magnetization is up (+) within the bubble and down (-) outside. The wall itself is composed of a set of Bloch segments of opposing polarity. These Bloch segments are separated from one another by 180° walls which are essentially Néel segments. In Fig. 1(b) we show the central spins through three Bloch segments separated by two Néel segments. We define  $\delta$  as the width of the Bloch wall, y as the length of a Bloch segment, and x as the length of a Néel segment.

As long as the sense of rotation of the spins around the bubble perimeter is maintained as either clockwise or counterclockwise, then this segmented configuration is frozen in; that is, it is stable against small spin perturbations. If we consider that both the Bloch and Néel segments are walls of uniform rotation,<sup>4</sup> then the wall energy density (energy per unit surface area of the perimeter wall) stored in each segment can be written as

$$\sigma_{\rm B} = \pi^2 A / \delta + \frac{1}{2} K \delta, \qquad (1)$$
  
$$\sigma_{\rm N} = \pi^2 A / \delta + \frac{1}{2} K \delta + \pi^2 A \delta / 2x^2 + \frac{1}{2} \pi M^2 \delta.$$

Here A is the exchange constant, K the uniaxial anisotropy (with  $\frac{1}{2}K$  being the effective anisotropy for spin rotation along the dimension  $\delta$ ),

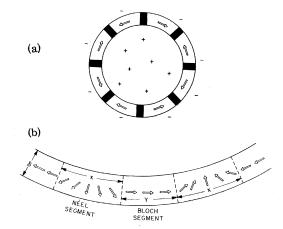


FIG. 1. (a) Top-view representation of a cylindrical magnetic bubble showing the perimeter Bloch wall with Néel segments (dark regions). (b) Representation of the spins in three Bloch wall segments separated by two Néel segments.